ISW /

Atty. Docket No. K35R1673.D1 (Formerly RDRT 1027-2) Appl. No. 10/656,311 **PATENT** 

MAR 2 8 2005

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yingjian CHEN

Application No.: 10/656,311

Examiner: Paul D. KIM

Group Art Unit: 3729

Filed:

September 5, 2003

Date: March 24, 2005.

Title:

Method for making high speed, high

areal density inductive write structure

**CERTIFICATE OF MAILING** 

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first class mail in an envelope addressed to: MS Amendment, Commissioner of Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on March 24, 2005.

Signed

Paula Faulk Hurley

MAIL STOP AMENDMENT COMMISSIONER FOR PATENTS P.O Box 1450 ALEXANDRIA, VA 22313-1450

## **AMENDMENT**

Dear Sir:

In response to the Office action mailed September 24, 2004, kindly amend the application as follows.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the claims are reflected in the **Listing of Claims** which begins on page 3 of this paper.

Remarks begin on page 9 of this paper.